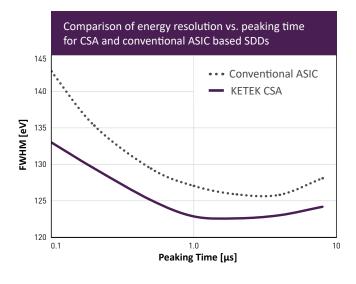




KETEK VITUS SILICON DRIFT DETECTORS (SDDs)

KETEK VITUS Silicon Drift Detectors (SDDs) are the state-of-the-art X-ray detectors for the energy range from 0.05 keV to 30 keV. They are used in manifold applications such as EDS, XRF, μ XRF and TXRF, in electron microscopes, benchtop systems, XRF handheld spectrometers as well as in recycling and mining material sorting installations. Due to their wide operating temperature range, their excellent energy resolution and high reliability they are particularly suited for industrial applications, even in harsh environments where the detectors experience very high ambient temperatures, shocks and vibrations.



GRAPHENE WINDOW TECHNOLOGY

■ Two window types available:

CH WINDOW

1 μm Carbon without support grid (replaces the 8 μm Beryllium window)

CL WINDOW

165 nm Carbon with Silicon support grid (86 % open area) for low energy applications

- Both window types allow vacuum encapsulation of detectors for excellent cooling performance
- Transmission better than conventional window types over whole energy range

KETEK PROPRIETARY CHARGE SENSITIVE AMPLIFIER (CSA)

- Significantly improved energy resolution, especially at short peaking times
- Extremely high throughput at appropriate DPP settings
- Fully compliant with conventional ASIC technology

NEW SDD COOLING TECHNOLOGY

- -60 °C SDD chip temperature achievable even at +65 °C heat sink temperature
- Drastically increased efficiency of the thermoelectric cooling (e.g. 250 mW at -35 °C sensor temperature)
- Ultra stable vacuum integrity for typically more than 10 years of operation







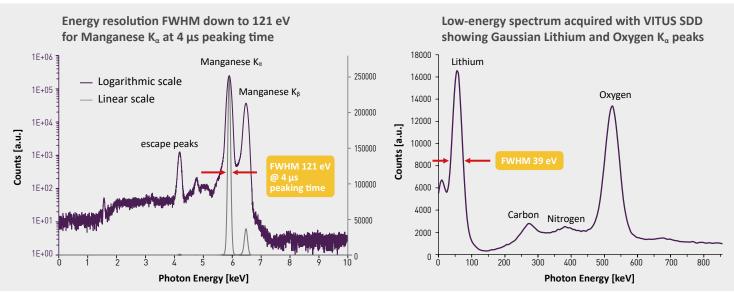


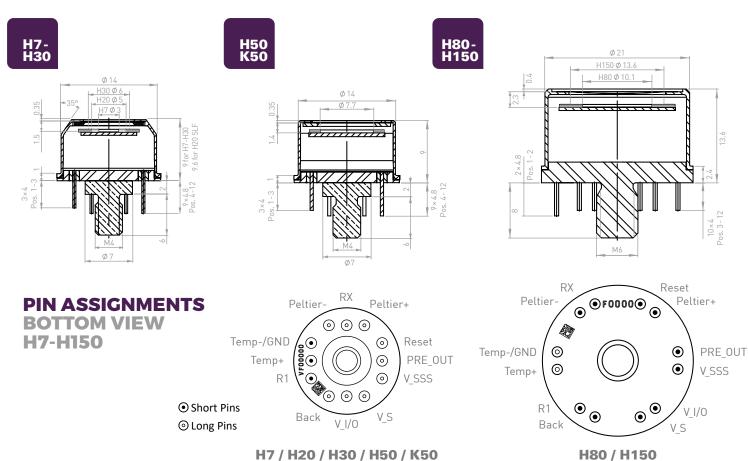






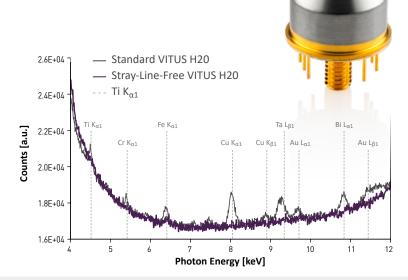
	H7 CH/CL	H20/H20 SLF CH/CL	H30 CH/CL	H50/K50 CH/CL	Н80	H150
COLLIMATED AREA [mm²]	7	20	28	47	80	143
ACTIVE AREA [mm²]	13	30	41	65	100	170



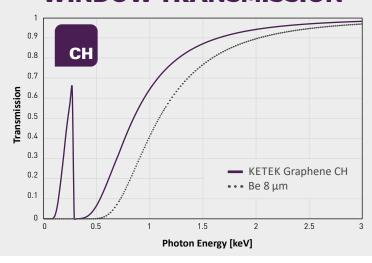


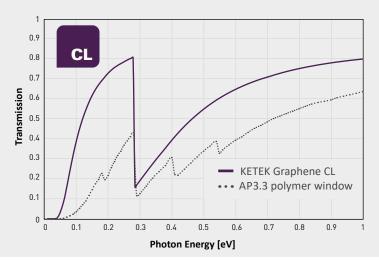
KETEK SLF STRAY-LINE-FREE MODULE

- Available for VITUS H20
- Elimination of nearly all unwanted X-ray fluorescence (stray lines) from internal SDD components
- Enables extremely low detection limits in the ppb regime
- Perfect for applications like:
 - → Rohs, Reach
 - \rightarrow Pharma
 - → Semiconductor industry
- Both Graphene window types (CH and CL) available
- Vacuum encapsulation allows He atmosphere operation



WINDOW TRANSMISSION





SPECIFICATIONS

On-chip collimator

Specifications for H7-H150		
First stage amplification	ASIC	
Energy resolution for H7-H50 and K50	≤ 129 eV @ Mn K _α	
Energy resolution for H80-H150	≤ 136 eV @ Mn K _α	
Peak to background	> 15,000	
Peak to tail	> 2,000	
Optimal peaking time at max. cooling	1 μs	
Absortion depth Si for H7 to H150	450 μm	
Absortion depth Si for K50	550 μm	
Peak shift stability up to 100 kcps	< 1 eV	
Max. input count rate	4,000 kcps	
Window for H7-H50 CH and K50 CH Window for H7-H50 CL and K50 CL Window for H80-H150	CH (1 μm Graphene) CL (165 nm Graphene) Be (25 μm Beryllium)	
Cooling performance	@ +20 °C heat sink $\Delta T > 95 \text{ K}$	

multilayer

Typical 300 parameters	Voitages	Currents	
Ring 1 (R1)	-20 V ± 10 V	10 μΑ	
Ring X (RX)	-130 V ± 30 V	10 μΑ	
Back	-80 V ± 20 V	< 1 nA	
Peltier element for H7-H50 and K50	5.5 V	600 mA max.	
Peltier element for H80-H150	9 V	1000 mA max.	
Temperature monitor	NTC thermistor 10 kΩ @ 25 °C		
Output signal	ramped reset type		
Output gain	1.6 mV/keV ± 20 %		





ORDER INFORMATION











H7 CH/CL	H20 CH/CL	H30 CH/CL	H50/K50 CH/CL	H80/H150
H7 CH V000-KTN0-H007-MA2C	H20 CH V000-KTN0-H020-MA2C		H50 CH V000-KTN0-H050-MA6C	H80 V000-KAT0-H080-ML4A
	H20 SLF V000-KTN0-H020-MEJC	H30 CH V000-KTN0-H030-MA2C	K50 CH V000-KTN0-K050-MA6C	
H7 CL V000-KTN0-H007-MA2G	H20 CL V000-KTN0-H020-MA2G	H30 CL V000-KTN0-H030-MA2G	H50 CL V000-KTN0-H050-MA6G	H150 V000-KAT0-H150-ML4A

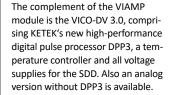
SDD ELECTRONICS

Description

VIAMP-KC/-KL 3.0 VITUS AMPLIFIER The VIAMP-KC/-KL 3.0 module combines a VITUS SDD (all sizes H7 to H150) and an ultra-low noise preamplifier of the latest generation 3.0 with improved biasing stability. The Aluminum housing functions as an efficient heat sink.

- VIAMP-KC 3.0 for H7 to H50
- VIAMP-KL 3.0 for H80 to H150
- Ramped reset type output signal
- Configurable via FFC interface
- Customized solutions available on request

VICO-DV 3.0 COMPLETE DPP ELECTRONICS BOARD



- KETEK's new DPP3 with peaking times down to 25 ns
- Extremely small dimensions 60 × 32 × 11 mm³
- Ethernet, USB and SPI interfaces
- Comprehensive programming library (VICOLib), acquisition software (VICOScope) and update tool (VICOUpdate) available for Windows and Linux



The AXAS 3.0 is KETEK's new all-inone system for VITUS SDDs in an ultra compact housing equipped with the latest generation 3.0 preamplifier technology. It is available with all VITUS SDDs from H7 to H50 and different lengths of the vacuum tight finger.

- Very small & complete XRF system: 81 × 61 × 36 mm³
- KETEK's new high-performance digital pulse processor DPP3 with peaking times down to 25 ns
- Ethernet and USB Type-C interface
- Mapping Mode for scanning applications
- Acquisition software (VICOScope) and update tool (VICOUpdate) available for Windows and Linux

ACCESSORIES

Product

Description

VMLCOL EXTERNAL COLLIMATOR



The clip-on mount for external multilayer collimators suits all VITUS SDDs up to the H50. Different collimator apertures are available. The VMLCOL prevents the excitation and fluorescence of the SDD's cap material.

- No stray lines from SDD cap
- Improved P/B and P/T
- Additional protection for the VITUS entrance window

VCGRID CARBON PROTECTION GRID



The pure carbon grid can be mounted within an instrument in front of the SDD in order to protect the window from mechanical impact.

- Open area > 75 %
- Thickness < 0.58 mm
- Withstands a static stress up to 50 N
- Customized grid designs available on request

